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General Description:

Pn infrared gallium arsenide light emitting diode optically coupled to an npn silicon photo darlington transistor, 1500 v min isolation voltage, 0.25 w power dissipation, -55 to 100 degrees c operating temp range, six-pin plastic case, 0.350 in. Maximum l, 0.310 in. Maximum w, 0.160 in. Maximum h

Specification Data:

80131-release 6464 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A23900